

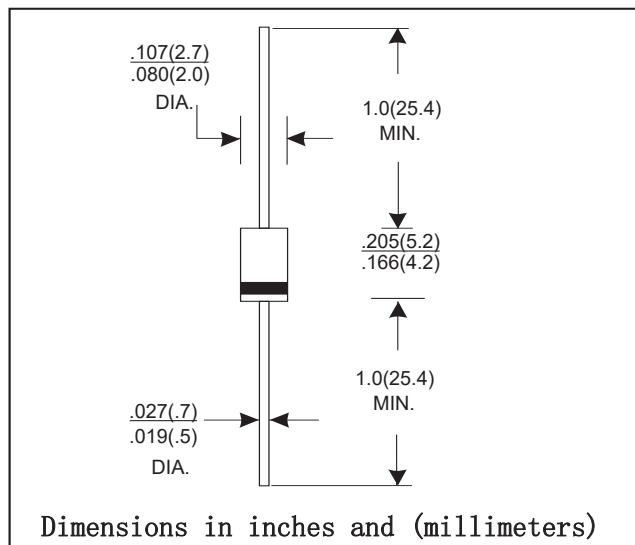
DO-41 High Efficient Rectifier Diodes

FEATURES

- The plastic package carries Underwrites Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- High reliability
- High temperature soldering guaranteed:260 °C/10 seconds at terminals
- Component in accordance to RoHs 2015/863 and WEEE 2012/19/EU

MECHANICAL DATA

- Case style: DO-41 molded plastic
- Mounting position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter		Symbol	HER 101	HER 102	HER 103	HER 104	HER 105	HER 106	HER 107	HER 108	UNITS
Maximum recurrent peak reverse voltage		V _{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS voltage		V _{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC blocking voltage		V _{DC}	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current.375"(9.5mm) Lead Length at Ta=50 C		I _{F(AV)}	1.0								A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load @T _j =125°C		I _{FSM}	30.0								A
Maximum Instantaneous Forward Voltage at 1.0A		V _F	1.0			1.3		1.7			V
Maximum reverse current at rated DC blocking voltage	@T _A =25°C	I _R	5.0								μA
	@T _A =100°C		150.0								
Maximum reverse recovery time		t _{rr}	50					75			ns
Typical junction capacitance		C _J	20								pF
Typical thermal resistance		R _{θJA}	50								°C/W
Operating junction temperature range		T _j	- 55 ---- + 150								°C
Storage temperature range		T _{STG}	- 55 ---- + 150								°C

RATINGS AND CHARACTERISTIC CURVES

FIG.1: FORWARD CURRENT DERATING CURVE

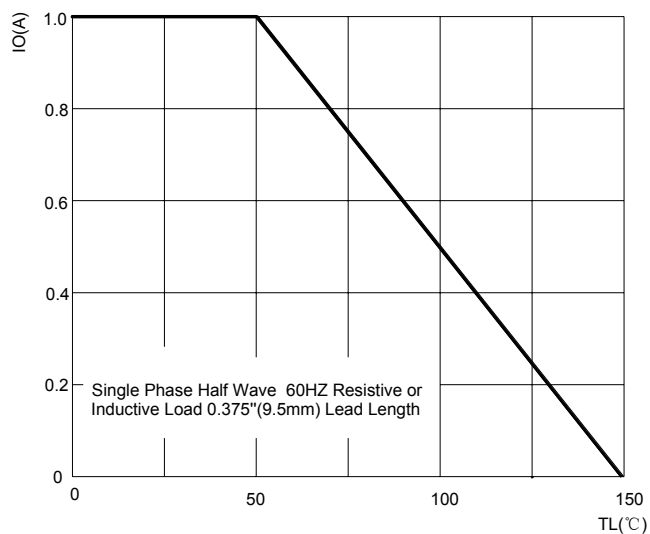


FIG.2: MAXIMUM NON-REPETITIVE FORWARD URGE CURRENT

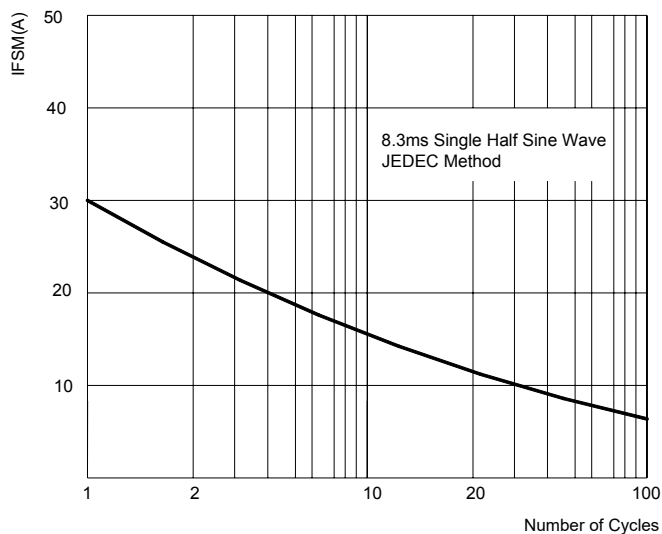


FIG.3: TYPICAL FORWARD CHARACTERISTICS

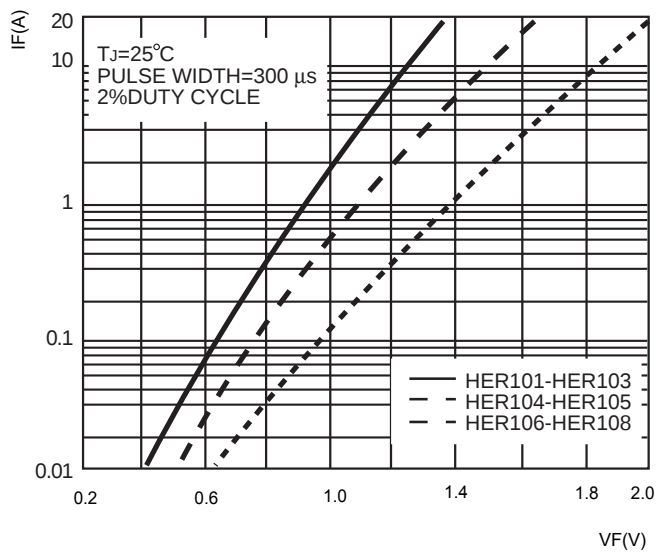


FIG.4: TYPICAL REVERSE CHARACTERISTICS

